查询TC7SG04FU供应商 TOSHIBA

### TC7SG04FU

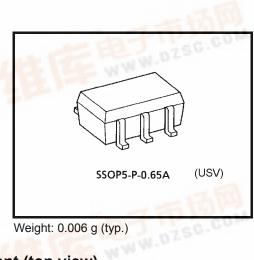
TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic



Inverter

#### Features

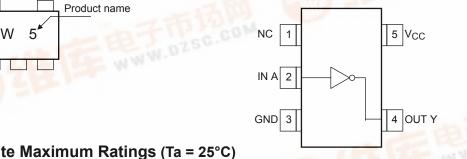
- $I_{OH}/I_{OL} = \pm 8 \text{ mA} (\text{min})$ High-level output current: at V<sub>CC</sub> = 3.0 V
- High-speed operation: t<sub>pd</sub> = 2.3 ns (typ.)
  - at V<sub>CC</sub> = 3.3 V,15pF Operating voltage range: V<sub>CC</sub> = 0.9~3.6 V
- 5.5-V tolerant input.
- 3.6-V power down protection output.



Weight: 0.006 g (typ.)

#### Marking

# Pin Assignment (top view)



#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit	
Power supply voltage	Vcc	-0.5~4.6	V	
DC input voltage	VIN	-0.5~7.0	V	
DC output voltage	Vour	-0.5~4.6 (Note 1)	V	
DC output voltage	Vout	-0.5~V <sub>CC</sub> + 0.5 (Note 2)		
Input diode current	I <sub>IK</sub>	-20	mA	
Output diode current	I <sub>OK</sub>	-20 (Note 3)	mA	
DC output current	IOUT	±25	mA	
DC V <sub>CC</sub> /ground current	ICC	±50	mA	
Power dissipation	PD	200	mW	
Storage temperature	T <sub>stg</sub>	-65~150	°C	

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the Note: significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

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Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### Note 1: $V_{CC} = 0V$ Note 2

VOUT < GND

Note 3.

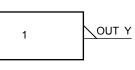
High or Low State. IOUT abusolute maximum rating must be observed.

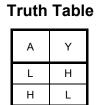
# <u>TOSHIBA</u>

# TC7SG04FU

### IEC Logic Symbol







### **Operating Ranges**

Characteristics	Symbol	Value	Unit	
Power supply voltage	V <sub>CC</sub>	0.9~3.6	V	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Output voltage	Varia	0~3.6 (Note 4)	V	
	Vout	0~V <sub>CC</sub> (Note 5)	v	
Output Current		±8.0 (Note 6)		
		±4.0 (Note 7)		
	1 /1	±3.0 (Note 8)	~ ^	
	I <sub>OH</sub> /I <sub>OL</sub>	±1.7 (Note 9)	mA	
		±0.3 (Note 10)		
		±0.02 (Note 11)		
Operating temperature	T <sub>opr</sub>	-40~85	°C	
Input rise and fall time	dt/dV	0~10 (Note 12)	ns/V	

Note 4:  $V_{CC} = 0V$ 

Note 5: High or Low state.

Note 6:  $V_{CC} = 3.0 \sim 3.6 \text{ V}$ 

Note 7:  $V_{CC} = 2.3 \sim 2.7 \text{ V}$ 

Note 8:  $V_{CC} = 1.65 \sim 1.95 \text{ V}$ 

Note 9: V<sub>CC</sub> = 1.4~1.6 V

Note 10: V<sub>CC</sub> = 1.1~1.3 V

Note 11:  $V_{CC} = 0.9 V$ 

Note 12:  $V_{IN} = 0.8 \sim 2.0 \text{ V}, \text{ V}_{CC} = 3.0 \text{ V}$ 

# <u>TOSHIBA</u>

### **DC Electrical Characteristics**

Characteristics Symbol Te		Test	t Condition		Ta = 25°C			Ta = −40~85°C		Unit
		Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
High-level input voltage				V <sub>CC</sub>	_	_	V <sub>CC</sub>	_	-	
			1.1~1.3	V <sub>CC</sub> × 0.7		_	V <sub>CC</sub> × 0.7	_		
	VIH	_		1.4~1.6	V <sub>CC</sub> × 0.65	_	_	V <sub>CC</sub> × 0.65	_	V
			1.65~1.95	$\begin{array}{c} V_{CC} \\ \times \ 0.65 \end{array}$	_	_	V <sub>CC</sub> × 0.65	_		
			2.3~2.7	1.7	_	_	1.7	_		
			3.0~3.6	2.0	_	_	2.0	—		
				0.9	_	_	GND		GND	
Low-level VIL input voltage				1.1~1.3	_		$V_{CC} \times 0.3$	_	$V_{CC} \times 0.3$	
	_		1.4~1.6			$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$	_	$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$	V	
			1.65~1.95			$\begin{array}{c} V_{CC} \\ \times \ 0.35 \end{array}$	_	V <sub>CC</sub> × 0.35		
					_	_	0.7		0.7	
			3.0~3.6			0.8		0.8		
High-level output voltage		VIN = VIL	I <sub>OH</sub> =-0.02 mA	0.9	0.75			0.75	_	v
			I <sub>OH</sub> = -0.3 mA	1.1~1.3	$\begin{array}{c} V_{CC} \\ \times \ 0.75 \end{array}$		—	V <sub>CC</sub> × 0.75	_	
	V <sub>ОН</sub>		I <sub>OH</sub> = -1.7 mA	1.4~1.6	$\begin{array}{c} V_{CC} \\ \times \ 0.75 \end{array}$		_	V <sub>CC</sub> × 0.75		
			I <sub>OH</sub> = -3.0 mA	1.65~ 1.95	V <sub>CC</sub> -0.45		—	V <sub>CC</sub> -0.45	_	
			I <sub>OH</sub> = -4.0 mA	2.3~2.7	2.0	_	_	2.0	_	
			I <sub>OH</sub> = -8.0 mA	3.0~3.6	2.48		_	2.48		
Low-level V <sub>OL</sub> output voltage			$I_{OL} = 0.02 \text{ mA}$	0.9	_	_	0.1	—	0.1	
			I <sub>OL</sub> = 0.3 mA	1.1~1.3	_	_	$\begin{array}{c} V_{CC} \\ \times \ 0.25 \end{array}$	_	$V_{CC} \times 0.25$	
	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OL</sub> = 1.7 mA	1.4~1.6			$\begin{array}{c} V_{CC} \\ \times \ 0.25 \end{array}$	—	$\begin{array}{c} V_{CC} \\ \times \ 0.25 \end{array}$	V
			I <sub>OL</sub> = 3.0 mA	1.65~ 1.95			0.45	—	0.45	
			$I_{OL} = 4.0 \text{ mA}$	2.3~2.7			0.4		0.4	
			I <sub>OL</sub> = 8.0 mA	3.0~3.6	_		0.4		0.4	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0~5.5V		0~3.6			±0.1	_	±1.0	μA
Power off leakage current	IOFF	$V_{IN} = 0 \sim 5.5 V$ $V_{OUT} = 0 \sim 3.6 V$		0		_	1.0	_	10.0	μA
Quiescent supply current	ICC	$V_{IN} = V_{CC}$ or GND		3.6	_		1.0	_	10.0	μA

# **TOSHIBA**

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = −40~85°C		Unit	
Characteristics			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
Propagation delay time		$C_L = 10 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	18.6		_	_	
			1.1~1.3	_	8.7	18.4	1.0	34.2	
			1.4~1.6	_	4.9	8.5	1.0	10.0	
			1.65~ 1.95	_	3.8	6.2	1.0	6.7	
			2.3~2.7	_	2.6	3.9	1.0	4.4	
			3.0~3.6	_	2.1	3.1	1.0	3.7	
			0.9	_	21.0		_	_	
	tргн tрнг	$C_L = 15 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	1.1~1.3	_	9.8	21.5	1.0	37.1	ns
			1.4~1.6	_	5.4	9.3	1.0	11.2	
			1.65~ 1.95	_	4.2	6.9	1.0	7.1	
			2.3~2.7	_	2.8	4.4	1.0	5.0	
			3.0~3.6	_	2.3	3.4	1.0	3.9	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	31.2		_	_	
			1.1~1.3	_	13.8	29.6	1.0	56.0	
			1.4~1.6	_	7.4	13.1	1.0	15.9	
			1.65~ 1.95	_	5.6	9.2	1.0	9.6	
			2.3~2.7	_	3.7	5.7	1.0	6.1	
			3.0~3.6		2.9	4.4	1.0	4.8	
Input capacitance	C <sub>IN</sub>		3.6	_	3			_	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 13)	0.9~3.6		6	_	_	_	pF

#### AC Electrical Characteristics (input $t_r = t_f = 3 \text{ ns}$ )

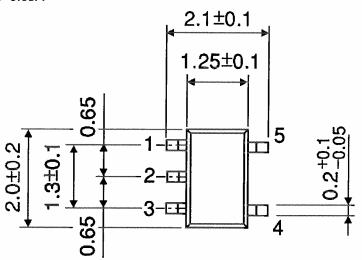
Note 13: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

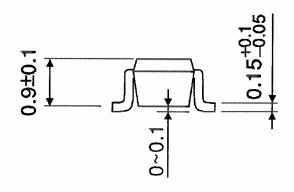
Average operating current can be obtained by the equation:  $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

# <u>TOSHIBA</u>

# Package Dimensions

SSOP5-P-0.65A





Weight: 0.006 g (typ.)

# TOSHIBA

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20070701-EN GENERAL

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